PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Satoshi TATSUURA, Yasuhiro SATO, Minquan TIAN and Prior Group Art Unit: 1741

Lyong Sun PU

Application No.: Rule 53(b) Divisional Application of

U.S. Application No. 09/571,864

Prior Examiner: E. Wong

Filed: February 26, 2002

Docket No.: 106200.01

For:

METHOD FOR ELECTRODEPOSITED FILM FORMATION, METHOD-FOR-

ELECTRODE FORMATION, AND APPARATUS FOR ELECTRODEPOSITED FILM

FORMATION ,

INFORMATION DISCLOSURE STATEMENT

Director of the U.S. Patent and Trademark Office Washington, D.C. 20231

Sir:

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Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference(s) listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference(s) be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

 \bowtie This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.

The references were cited by or submitted to the Office in parent application No. 09/571,864, filed May 16, 2000, which is relied upon for an earlier filing date under 35 U.S.C. §120. Thus, copies of these references are not attached. 37 CFR §1.98(d).

espectfully submitted.

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	(Use several sheets if necessary)			APPLICANTS Satoshi TATSUURA, Yasuhiro SATO, Minquan TIAN, and Lyong Sun PU						
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